# 1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection in a DSN0603-2 (SOD962-2) leadless ultra small Surface-Mounted Device (SMD) package.

#### 2. Features and benefits

- Average forward current I<sub>F(AV)</sub> ≤ 0.2 A
- Reverse voltage V<sub>R</sub> ≤ 20 V
- Low forward voltage typ. V<sub>F</sub> = 245 mV
- Low reverse current typ. I<sub>R</sub> = 5 μA
- · Ultra small and leadless SMD package
- Package height typ. 0.3 mm

# 3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Low power consumption applications
- Ultra high-speed switching
- LED backlight for mobile application

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; f = 20 kHz; $T_{amb}$ = 115 °C; square wave	[1]	-	-	0.2	А
		$\delta$ = 0.5 ; f = 20 kHz; $T_{sp}$ = 125 °C; square wave		-	-	0.2	А
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C		-	-	20	V
V <sub>F</sub>	forward voltage	$I_F$ = 10 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_j$ = 25 °C		-	245	310	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 10 V; T <sub>j</sub> = 25 °C		-	5	-	μA

[1] Device mounted on a ceramic Printed-Circuit Board (PCB),  $Al_2O_3$ , standard footprint.





# 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]		1 <del>][-]</del> 2
2	Α	anode		sym001
			Transparent top view	
			DSN0603-2 (SOD962-2)	

<sup>[1]</sup> The marking bar indicates the cathode.

# 6. Ordering information

Table 3. Ordering information

Type number	Package	ackage				
	Name	Description	Version			
PMEG2002AESF	DSN0603-2	Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm	SOD962-2			

# 7. Marking

Table 4. Marking codes

Type number	Marking code
PMEG2002AESF	A

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_R$	reverse voltage	T <sub>j</sub> = 25 °C		-	20	V
I <sub>F</sub>	forward current	T <sub>sp</sub> ≤ 120 °C		-	0.28	Α
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; f = 20 kHz; $T_{amb}$ = 115 °C; square wave	[1]	-	0.2	Α
		$\delta$ = 0.5 ; f = 20 kHz; $T_{sp}$ = 125 °C; square wave		-	0.2	А
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ ms}; \ \delta \le 0.25$		-	2	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	4.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[2]	-	325	mW

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Symbol	Parameter	Conditions		Min	Max	Unit
			<u>[3]</u>	-	525	mW
			[1]	-	950	mW
T <sub>j</sub>	junction temperature			-	125	°C
T <sub>amb</sub>	ambient temperature			-55	125	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

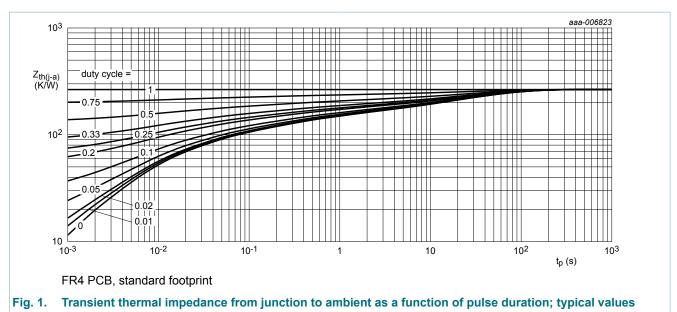
- [1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al<sub>2</sub>O<sub>3</sub>, standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm<sup>2</sup> each.

### 9. Thermal characteristics

Table 6. Thermal characteristics

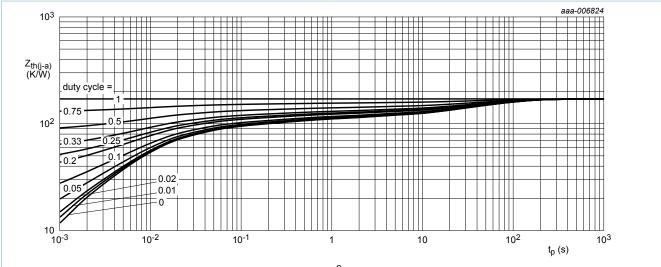
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient		in free air	[1][2]	-	-	310	K/W
		[1][3]	-	-	190	K/W	
	ambient		[1][4]	-	-	105	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		[5]	-	-	40	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm<sup>2</sup> each.
- [4] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.
- [5] Soldering point of cathode tab.



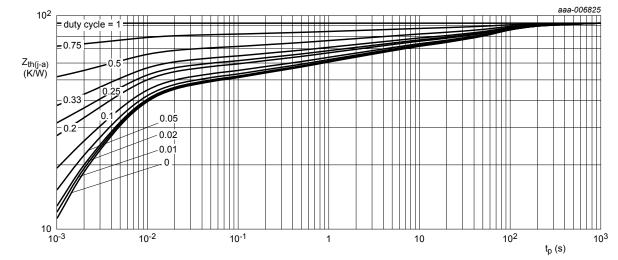
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FR4 PCB, mounting pad for anode and cathode 1 cm<sup>2</sup> each

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

# 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage	$I_F$ = 0.1 mA; pulsed; $t_p \le 300 \ \mu s$ ; $\delta \le 0.02$ ; $T_j$ = 25 °C	-	120	180	mV
		$I_F$ = 1 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_j$ = 25 °C	-	180	250	mV
		$I_F$ = 10 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_j$ = 25 °C	-	245	310	mV
		$I_F$ = 100 mA; pulsed; $t_p \le$ 300 μs; $δ \le$ 0.02 ; $T_j$ = 25 °C	-	330	380	mV
		$I_F$ = 200 mA; pulsed; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_j$ = 25 °C	-	375	420	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 6 V; T <sub>j</sub> = 25 °C	-	3.2	20	μA
		V <sub>R</sub> = 10 V; T <sub>j</sub> = 25 °C	-	5	-	μA
		V <sub>R</sub> = 20 V; T <sub>j</sub> = 25 °C	-	10	45	μA
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	25	-	pF
		V <sub>R</sub> = 10 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	10	-	pF
t <sub>rr</sub>	reverse recovery time	$I_F$ = 200 mA; $I_R$ = 200 mA; $I_{R(meas)}$ = 40 mA; $T_j$ = 25 °C	-	1.9	-	ns

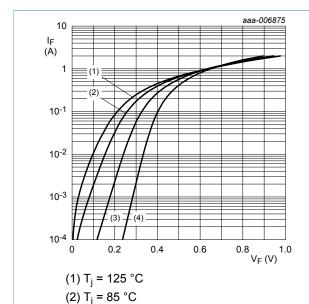
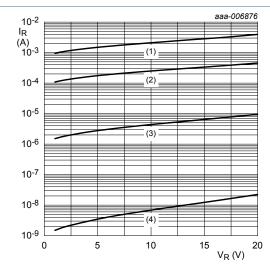


Fig. 4. Forward current as a function of forward voltage; typical values

(3)  $T_j = 25 \, ^{\circ}C$ 

(4)  $T_i = -40 \, ^{\circ}C$ 



(1)  $T_i = 125 \,^{\circ}C$ 

(2)  $T_i = 85 \, ^{\circ}C$ 

(3)  $T_j = 25$  °C

(4)  $T_j = -40 \, ^{\circ}C$ 

Fig. 5. Reverse current as a function of reverse voltage; typical values

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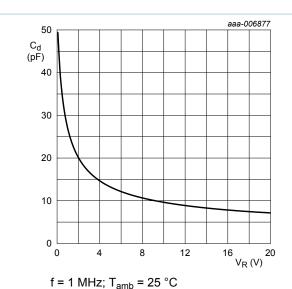
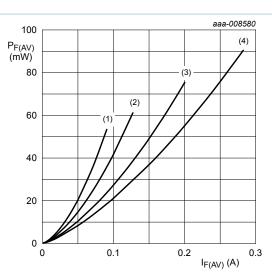


Fig. 6. Diode capacitance as a function of reverse voltage; typical values



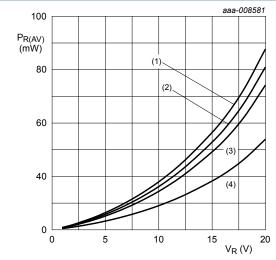
 $T_j = 125 \,^{\circ}\text{C}$ (1)  $\delta = 0.1$ 

 $(2) \delta = 0.2$ 

 $(3) \delta = 0.5$ 

 $(4) \delta = 1$ 

Fig. 7. Average forward power dissipation as a function of average forward current; typical values



T<sub>i</sub> = 125 °C

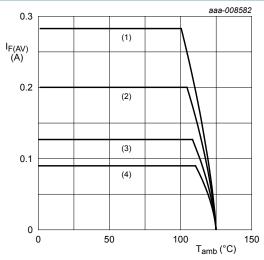
 $(1) \delta = 1 (DC)$ 

(2)  $\delta$  = 0.9; f = 20 kHz

(3)  $\delta$  = 0.8; f = 20 kHz

(4)  $\delta$  = 0.5; f = 20 kHz

Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

T<sub>j</sub> = 125 °C

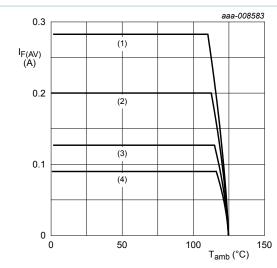
 $(1) \delta = 1$ 

 $(2) \delta = 0.5$ 

 $(3) \delta = 0.2$ 

 $(4) \delta = 0.1$ 

Fig. 9. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for anode and cathode 1

cm2 each

T<sub>i</sub> = 125 °C

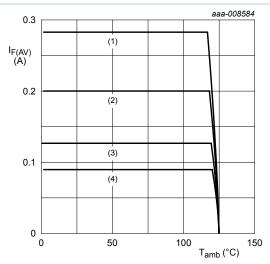
 $(1) \delta = 1$ 

 $(2) \delta = 0.5$ 

 $(3) \delta = 0.2$ 

 $(4) \delta = 0.1$ 

Fig. 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

 $T_{i} = 125 \, ^{\circ}\text{C}$ 

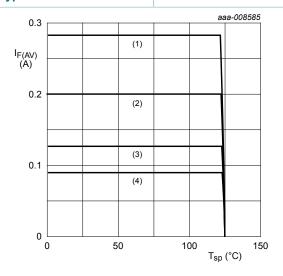
 $(1) \delta = 1$ 

 $(2) \delta = 0.5$ 

 $(3) \delta = 0.2$ 

 $(4) \delta = 0.1$ 

Fig. 11. Average forward current as a function of ambient temperature; typical values



T<sub>i</sub> = 125 °C

 $(1) \delta = 1$ 

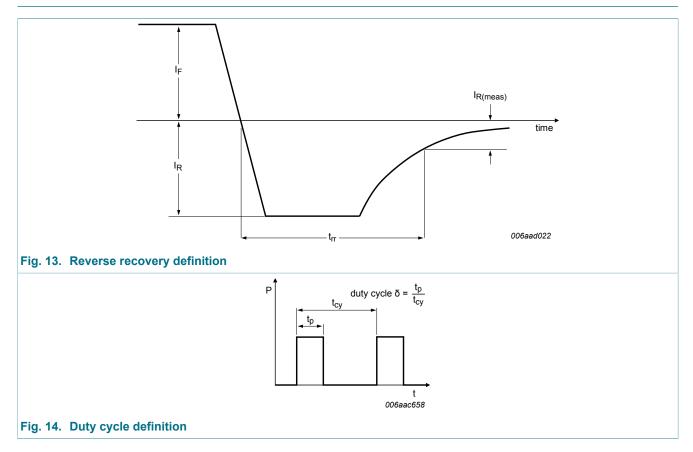
 $(2) \delta = 0.5$ 

 $(3) \delta = 0.2$ 

 $(4) \delta = 0.1$ 

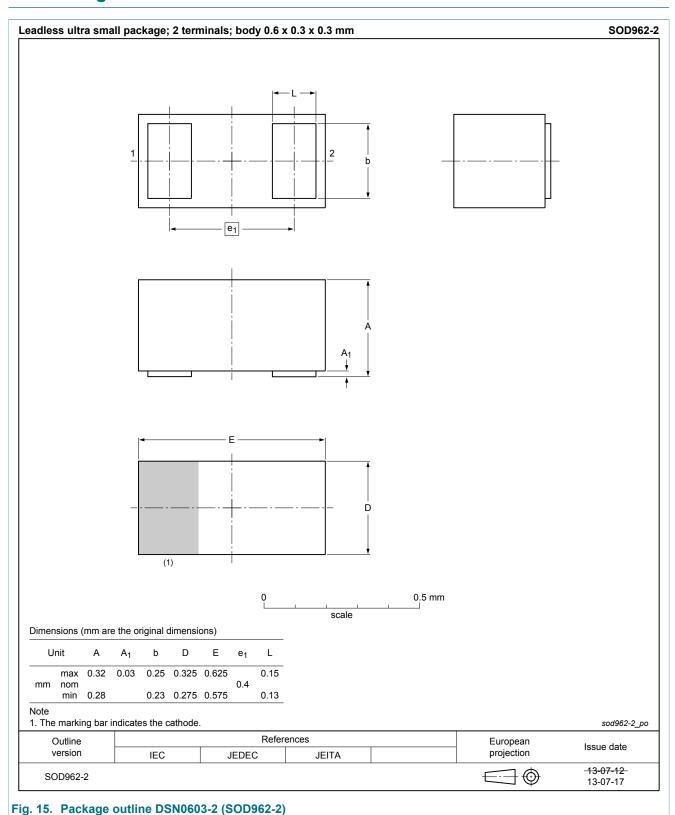
Fig. 12. Average forward current as a function of solder point temperature; typical values

# 11. Test information



The current ratings for the typical waveforms are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

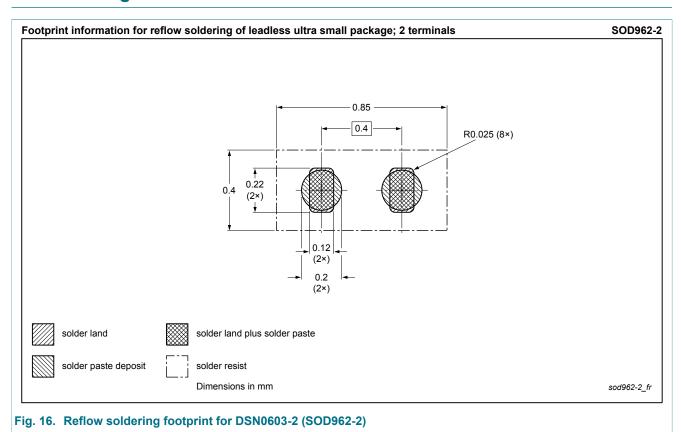
# 12. Package outline



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# 13. Soldering



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# 14. Revision history

#### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMEG2002AESF v.3	20140122	Product data sheet	-	PMEG2002AESF v.2		
Modifications:	<ul> <li>Features and benef</li> </ul>	Features and benefits: corrected				
PMEG2002AESF v.2	20131008	Product data sheet	-	PMEG2002AESF v.1		
PMEG2002AESF v.1	20130301	Objective data sheet	-	-		

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## 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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